The electroclinic e ect and modulated phases in sm ectic liquid crystals

Robert B. Meyer

The Martin Fisher School of Physics, Brandeis University, Waltham, Massachusetts 02254-9110

Robert A. Pelcovits

Department of Physics, Brown University, Providence, RI 02912

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We explore the possibility that the unusually large electroclinic e ect observed in the sm ectic(A phase of a ferroelectric liquid crystal arises from the presence of an ordered array of disclination lines and walls in a sm ectic(C phase. If the spacing of these defects is in the subvisible range, this modulated sm ectic(C phase would be similar m acroscopically to a sm ectic(A phase. The application of an electric eld distorts the array, producing a large polarization, and hence a large electroclinic e ect. We show that with suitable elastic parameters and su ciently large chirality, the modulated phase is favored over the sm ectic(A and helically tw isted sm ectic(C phases. We propose various experimental tests of this scenario.

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I. IN TRODUCTION

Chiral liquid crystals exhibit a variety of interesting phenomena [1]. Chiral molecules tend to pack at a slight angle with respect to their neighbors. This preferred packing leads to spontaneous twist in the molecular orientation, producing phases such as the cholesteric and helically twisted smectic (C (Sm {C). In the case of two (dimensional Sm {C Im s, the chiral modulation of the molecular orientation cannot occur in a defect (free fashion. Instead, for large chirality, the system will form a modulated phase consisting of a regular network of defect walls and possibly points. One possible modulated phase is a \striped" phase consisting of a regular array of parallel dom ain walls (Fig. 1). In between these walls the c director rotates in the sense preferred by the chirality. A nother possible modulated phase consists of a hexagonal array of dom ain walls, with point defects located at the centers and corners of the hexagonal cells (Fig. 2).

Chirality also leads to unusual e ects in orientationally disordered phases. As shown by G aro and M eyer [2] using symmetry arguments, if an electric eld is applied to a system of chiral molecules in the Sm {A phase, an average molecular tilt will be produced, a response term ed the electroclinic e ect. These symmetry arguments do not, how ever, indicate the microscopic basis of the electroclinic e ect. To date, two microscopic models have been proposed. In the rst, the long axes of the molecules are assumed to be perpendicular to the smectic layers in the Sm {A phase. The electric eld causes the molecules to tilt, with an accompanying signi cant change in the smectic layer spacing. In the second scenario suggested by de Vries β], the molecules in the Sm {A phase are assumed to be tilted even in the absence of the electric eld, but azim uthally disordered. The electric eld then induces azim uthal order, with no signi cant change in the smectic layer spacing. Experimental studies have shown evidence for both models, at least

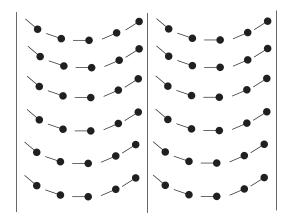


FIG.1: Striped modulated phase in a thin Sm {C lm. The circular heads of the objects shown denote the heads of the local c director; the vertical lines are domain walls where the c director rotates by an angle of order .

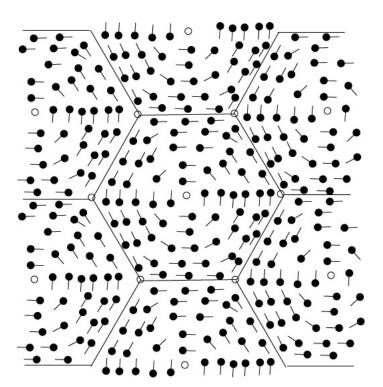


FIG.2: Hexagonalm odulated phase in a thin Sm {C lm. There is a + 1 disclination at the center of each unit cell, and 1=2 disclinations at each corner. Domain walls where the c director rotates by an angle of order bound the cell.

in term s of the eld{induced layer contraction. Recently Selinger et al. [4] noted that the optical birefringence of the liquid crystal will also distinguish between the two m icroscopic pictures. Because the eld induces orientational order in the second m odel while sim ply tilting the already aligned m olecules in the rst, the birefringence should change dram atically in the form erm odel, but not the latter. It appears that each of these m odels has experim ental validity, namely there are m aterials with substantial layer contraction and weak eld dependence in the birefringence, and otherm aterials with the opposite properties. How ever, even a detailed theory based on the second m odel [4] is unable to fully describe the experimental data. Furtherm ore, m any m aterials show an unusually large electroclinic e ect, well into the Sm {A phase. W hile it is tempting to associate this large e ect with strong critical uctuations [4], a completely di erent m olecular m echanism m ay be relevant.

In this paper we propose a new model for the microscopic origin of the electroclinic elect, one that shares some of the macroscopic characteristics of the de Vries scenario, speci cally, no layer contraction and eld dependent birefringence. We postulate that what is assumed to be a Sm {A phase in some materials close to the Sm {C A transition, could in fact be a modulated version of the smectic{C phase, a network of defects, walls and lines, but one where the spacing between the defects is in the subvisible range. This modulated phase would have no long range azim uthal order or net polarization in the absence of an electric eld. Thus, \to the eye", this phase would appear to be a Sm {A phase. However, the application of an electric eld distorts the structure of the defect array and leads to a large electroclinic elect. We now describe our proposed modulated phase and its response to an electric eld in detail.

A bulk chiral Sm {C can be described by the following elastic free energy [5]:

$$F = \frac{2}{d^3x} \frac{1}{2} K_1 (r - c) + \frac{1}{2} K_2 (c - r - c + d) + \frac{1}{2} K_{13} (c - r - c) (c - r - c) + \frac{1}{2} K_3 (c - r - c) + \frac{1}{2} K_3 (c - r - c) (c$$

where c is the projection of the nem atic director on the plane of the layers. We assume that the molecular tilt is uniform and thus c is assumed to be of xed length. Chirality appears in two terms in this free energy. First, chirality induces a spontaneous twist of the c director as indicated in the second term on the right hand side of Eq. (1), which is minimized in a helical state with pitch 2 =q. Second, chirality induces spontaneous bend within each smectic layer as indicated by the last term in the free energy, where we assume w > 0. The free energy as written is zero for the perfect helical state with pitch 2 =q. Because the sm ectic{C phase is ferroelectric, with the spontaneous polarization perpendicular to c, we must add to this free energy an electrostatic term arising from space charge density proportional to \hat{z} r c. We ignore this term for now, since we will nd that in our proposed modulated phase, it adds only a constant to the free energy density, independent of the detailed structure of our model.

Considerable work has been done on analyzing Eq. (1) in two {dimensional chiral smectic liquid crystals, where the term sproportional to K₂ and K₁₃ in the free energy above are absent, and thus, there will be no competition between the two chiral terms. While only one chiral term is present, it is in possible to in pose a spontaneous bend throughout the system . Defects must be introduced which separate dom ains of spontaneous bend, thus leading to a modulated phase. Two types of modulated phases have been proposed, a \striped" phase (Fig. 1) with a one{dimensional m odulation [6, 7, 8], and a hexagonal phase (Fig. 2) with a two {dimensional modulation. In the form er case, parallel dom ain walls separate regions of spontaneous bend, while the latter consists of a two{dim ensional array of dom ain walls and point disclinations. A + 1 point disclination lies at the center of each hexagonal cell, while the boundaries of the cell are dom ain walls where the c director rotates by (a description of internal structures of these walls in terms of a non xed length c director eld is given in [7,8]). A $\frac{1}{2}$ point disclination is located at each corner of the cell. The hexagonal phase which involves nearly pure bend is favored over the striped phase when K $_1$ K₃. The size of the unit cell is inversely proportional to the strength of the chirality parameter w. The free energy of the hexagonal lattice includes (see Eq. (5) below) an attractive logarithm ic interaction between the +1 disclination at the center of the cell and the $\frac{1}{2}$ disclinations at the corners. Thus, strongly chiral materials, where the unit cell is small, will favor this interaction, and hence the hexagonal phase [1].

Returning to the fullthree{dim ensional free energy, Eq. (1), we consider the possibility of a modulated phase. A bulk m odulated phase must somehow comprom ise between the two competing chirality{induced tendencies: spontaneous in{layer bend and spontaneous twist about the layer normal. To describe the electroclinic e ect in our proposed scenario the bulk modulated phase must have zero net polarization. Thus, a bulk modulated phase produced by simply extending the two{dim ensional striped phase in the third direction is not acceptable, even if the pitch of the spontaneous twist were assumed to be in nitely large. A three{dim ensional model for a thick chiral smectic lm was proposed in Ref. [9], where the in{plane modulation and dom ain walls are con ned to surface regions, and the director twists in the interior of the lm. Here we consider a space{ lling modulated structure, with no need for surface structures.

Our starting point in constructing a suitable bulk modulated phase is the director con guration of the +1 point disclination at the center of the two{dimensional hexagonal cell (Fig. 2). Expressing the c director as $c = (\cos (x;y); \sin (x;y))$, the angle is given by:

$$(x;y) = (x;y) + _{0};$$
 (2)

where the polar angle (x;y) is given by $(x;y) = \arctan(y=x)$, and $_0 = =2$ (for the sign of the chirality appropriate to the structure shown in Fig. 2; for the opposite sign of chirality, $_0 = =2$, and the director circulation will be clockwise). This con guration represents pure bend and describes the director con guration away from the dom ain walls which bound the unit hexagonal cell. We now form a three{dimensional simple hexagonal lattice, with a unit cell of height h, and cross{sectional area as in the two{dimensional case. We specify the director con guration as follows. In the midplane of the unit cell (taken to be the z = 0 plane) we assume the perfect bend director con guration of Eq. (2). We then introduce twist in the z direction, by writing the angle (x;y;z) of the c director as follows:

$$(x;y;z) = (x;y) + _{0}(z);$$
 (3)

with

$$_{0}(z) = =2 + z = '; \quad h=2 < z < h=2:$$
 (4)

The pitch 'of this helical structure will be determ ined by minim izing the free energy density of the unit cell. W ith this model for the modulated phase, the K₁₃ and w terms in the free energy, Eq. (1), can be combined into a term like the w term with $w_{eff} = w + =$ '. We not that 'is so large that for simplicity we set $w_{eff} = w$.

Thus the unit cellhas a + 1 disclination line running along the central z axis of the cell and parallel 1=2 disclination lines along the edges of the cell. W ithin the cell the director twists along the z axis, in the sense preferred by the chirality (see Fig. 3). The top and bottom faces of the cell (perpendicular to the z axis) are domain walls where the director undergoes a rotation by 2 h=`. The six other faces of the cell are walls where the c director rotates by .

The free energy density of the hexagonal unit cell (of side R) relative to the helical state is given by:

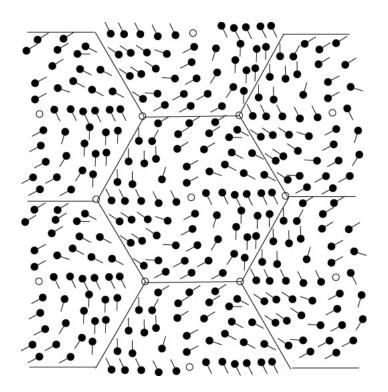


FIG.3: A slice through the bulk hexagonal lattice at z = = -6, showing how the director has twisted by an angle of = 6 relative to the z = 0 slice shown in Fig.2.

$$f = \frac{2 K \ln (R = R_{o}) + K^{0}}{3 \frac{P}{3R^{2} = 2}} + K_{2} q \frac{2}{2} \frac{2}{2} \frac{2 \ln 3w}{hR} \sin (h=2) + \frac{2A_{T}}{h} + \frac{2A_{S}}{\frac{P}{3R}};$$
(5)

where we have assumed that $K_1 = K_3 = K$ to simplify the elastic energy expression associated with the disclination lines. The core size of the disclination lines is denoted by R_o , and we represent the domain wall energy per unit area of the top and bottom faces of the cell by A_T , and the wall energy per unit area of each side face by A_S . The term proportional to $\ln (R = a)$ includes the elastic energy per unit cell associated with the +1 disclination line at the center of the cell and the surrounding 1=2 disclination [8]. The term K^0 represents the rem and of the splay (bend elastic energy per unit cell. The term proportional to w is obtained by integrating the corresponding term in Eq. (1) over the hexagonal unit cell using the director pro le Eq. (3), thus ignoring the distortion of this pro le near the edges of the cell.

Before m inimizing this free energy density we consider the response of the modulated state to an electric eld, i.e., the electroclinic e ect. We assume that the direction of the molecular dipole moment p is given by c 2. In the two{dimensional hexagonal modulated phase (see Fig. 2), the molecular dipole moments near the center of the cell will point radially outward, given the bend con guration of the c director. Thus, an electric eld applied in the +x direction will shift each +1 disclination in the opposite direction, inducing a net polarization in the +x direction, as shown in Fig. 4. For the three{dimensional cell we assume that the +1 disclination lines at the cell centers also shift rigidly in the opposite direction to the eld, ignoring any possible bending of the line due to the twist of the director in each cell (this should be a higher{order e ect in the electric susceptibility). A ssum ing that the disclination lines shift by a distance d in the x direction, we nd that the polarization (the net dipole moment of a cell divided by its volum e V) is given to leading order in d by:

$$P = \frac{2dp'R}{Va^{3}}\sin(h=2');$$
 (6)

where p is the molecular dipole moment and a is the average interm olecular spacing. In deriving P we have assumed that the unit cell is a cylinder of radius R centered on the original position of the line; ignoring the hexagonal shape of the cell merely changes the num erical prefactor appearing in the above expression.

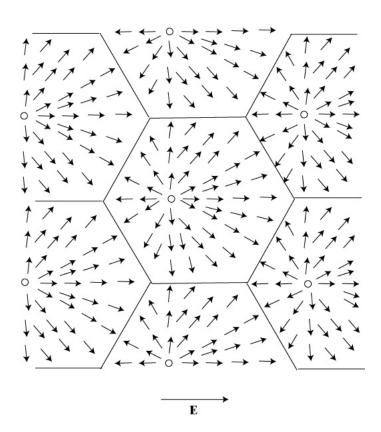


FIG.4: The z = 0 slice through the bulk hexagonal lattice in the presence of an electric eld in the + x direction. The arrows here represent the molecular dipole moments which are locally perpendicular to the c director and lie in the x y plane. The electric eld shifts the disclination line at the center of each cell to induce a net polarization in the direction of the eld.

The distance d is determined by minimizing the change in the free energy density due to the presence of the eld. D isplacing the disclination line by a distance d costs elastic energy proportional to K h (d=R)². Thus, d is given by:

$$d = \frac{p E R^{3}}{K ha^{3}} \sin(h=2');$$
(7)

the polarization by:

$$P = \frac{p^2 \cdot {}^2 R^2 E}{K a^6 h^2} \sin^2 (h=2');$$
(8)

and the susceptibility by:

$$_{P} \qquad \frac{dP}{dE} = \frac{p^{2} {}^{2}R^{2}}{K a^{6}h^{2}} \sin^{2} (h=2'):$$
(9)

We now consider the minimization of f, which is a function of R; '; and h. Minimizing rst with respect to R, we nd the following condition:

$$R = \frac{4 K}{3 f_{W}} \ln (R = R_{\circ}^{0}); \qquad (10)$$

where

$$f_{W} = \frac{w \sqrt{3 \ln 3}}{h} \sin(h=2) A_{S}; \qquad (11)$$

and

$$R_{o}^{0} = R_{o} \exp \frac{1}{2} - \frac{K^{0}}{2K}$$
 : (12)

6

Eq.(10) has a solution for $R > R_0^0$ providing $f_W > 0$. This condition is physically equivalent [7] to requiring that the dom ain wallenergy of the side walls of the cellbe negative in a non { xed length directorm odel, where the wallenergy includes surface contributions, i.e., contributions from the total gradient term r c. Num ericalm in imization of the free energy density, Eq. (5), with respect to R; '; and h, (choosing K = K₂ = 1; K⁰ = A_T = A_S = 0:1) indicates that for values of w that yield f < 0, (i.e., when the modulated state is favored over the helical state), h 10° ; '=h 100, and:

$$\frac{2}{h}\sin(h=2)$$
 1: (13)

The condition ' h is sensible, because in that case the director pattern in each cell will be nearly pure bend. In this lim it the condition $f_W > 0$ in plies that $A_S < w^2 3 \ln 3 = 2$ w.

W ith 'very large, the polarization space charge density, proportional to $2 ext{ r}$ c varies in each cell as 1=r, w ith r the distance from the central disclination, and is alm ost independent of z. This produces an electric eld E which is alm ost purely radial, and constant in magnitude, considering the cell to be approximated by a cylinder. At the outer boundary of the cell there is a surface charge which precisely cancels the charge in the interior of the cell, so that there is no electric eld outside each cell due to the charge distribution within the cell and on its boundaries. Thus the electrostatic energy density can be evaluated in a single cell, and is proportional to E^2 , independent of the radius or height of the cell. A though there are also ionic charges present in liquid crystals, typical estimates of their screening length indicate that they would not alter the electric elds at the length scales we are considering.

A ssum ing that ' is large, as indicated by the num ericalm inim ization of Eq. (5), (speci cally, ' q^1), and using Eq. (13), the free energy density Eq. (5) can be approximated as:

$$f = K_2 q^2 + \frac{P_0^2}{8} = \frac{P \overline{3} f_W^2 (2 \ln (R = R_0^0) - 1)}{8 \kappa \ln^2 (R = R_0^0)};$$
(14)

in which the electrostatic term, with spontaneous polarization density P_0 and dielectric constant , has been included.

We determ ine R by numerically solving Eq. (10), using Eq. (13), and choosing K = 1; $K^0 = A_s = 0$:1 and $K_2q^2 + P_0^2 = (8_{-}) = 0.0025$; the results are shown in Fig. 5. Using these results for R we obtain the approximate free energy density, Eq. (14), as a function of w (as shown in Fig. 6, choosing $K_2 = 1$; $A_T = 0$:1). We see that if w > 0.39, the hexagonal phase is favored over the helical state. The numerical minimization of the full expression for the free energy, Eq. (5), indicates that in this phase h 10^6 , in units of an interm olecular spacing. Thus, the hexagonal phase in a real system would likely consist of a single lattice plane of hexagonal cells, i.e., the system is e ectively two{dimensional.

From Eqs. (9) and (13) we see that:

$$_{\rm P}$$
 R²: (15)

We plot $_{\rm P}$ as a function of w in Fig. 7.

II. CONCLUSIONS

Returning now to the observations that m otivated this work, we can see that if R is a sub-visible length, then the m odulated phase would resemble a Sm {A phase, optically. In our model, the apparent Sm {A to Sm {C transition, as tem perature is low ered, would actually be m in icked by the gradual change of physical parameters, so that below the transition tem perature, the helical Sm {C phase would have low er free energy than the m odulated phase.

In our model, this would be a rst order transition. Since the driving term in the free energy density, Eq. (5), favoring the modulated phase is the term proportional to w, one could say that if w decreases as temperature is lowered while all other parameters remain constant, then when w passes through a particular value (about 0.39 in our calculated example) a rst order transition to the helical Sm {C phase would occur. Approaching this transition, R would be increasing, as would the susceptibility, $_{P}$, as seen in the gures above.

The value of R could well remain sub-visible throughout the range of the modulated phase. The electroclinic e ect could be large throughout the temperature range of the modulated phase, with a rapid increase as the transition to the helical Sm {C phase is approached. The mean smectic layer spacing would be almost constant through the phase transition. In the modulated phase it would be governed by an average between the layer spacing in the bulk and that in the side walls of the hexagonal cells, in which it is probably larger, due to a smaller molecular tilt angle. Therefore, at the phase transition, when the walls disappear, a very slight decrease in mean layer spacing would result. Q ualitatively, these features agree with observations.

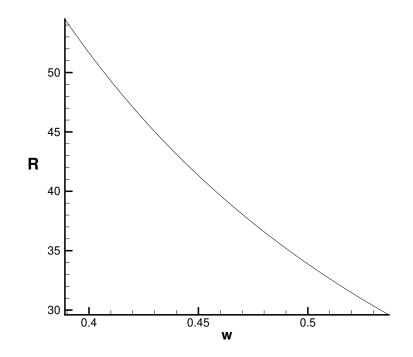


FIG. 5: The side R of the hexagonal unit cell determ ined by numerically solving Eq. (10), using Eq. (13), and choosing K = 1; $K^0 = A_s = 0$:1 and $K_2q^2 + P_0^2 = (8) = 0$:0025.

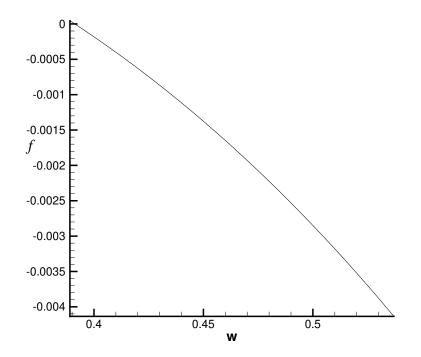


FIG.6: The approximate free energy density Eq. (14) as a function of w. The side R of the unit cell is determined numerically from Eq. (10). The parameters used in Eqs. (10) and (5) are: $K = K_2 = 1$; $K^0 = A_T = A_S = 0$: 1 and $K_2q^2 + P_0^2 = (8) = 0.0025$.

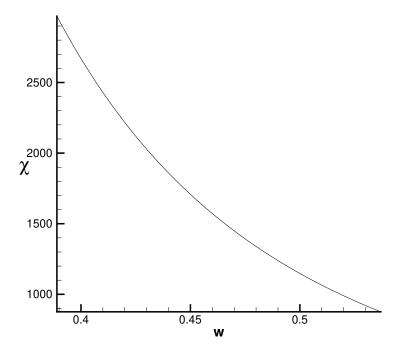


FIG.7: The susceptibility $_{\rm P}$ in arbitrary units as a function of w, determ ined from Eq.15) and the numerical solution of Eq.10).

O ne could try to orchestrate a more physically appealing model of how the parameters of the free energy might change with temperature. For instance, A_s steadily increasing would have essentially the same result as w steadily decreasing. More generally, any combination of $K_2q^2 + P_0^2 = (8)$ increasing and/or f_W decreasing with falling tem – perature could produce the qualitative features of the apparent Sm {A phase and the phase transition.

The most valuable test for the validity of this model in realmaterials would be the direct observation of the periodic structure of the modulated phase. The stappropriate sub-optical probe that comes to mind is small angle X-ray direction, especially resonant X-ray direction that is most sensitive to variations of molecular orientation in a structure [10]. Hiroshi Yokoyama [11] has pointed out to us that atom ic force microscopy might also be a suitable probe, if the modulated phase structure is preserved in a thin layer deposited on a substrate.

R em arkably, in a recent paper [12] on one of them aterials whose properties stimulated this work, optical observations consistent with a modulated phase, just at the transition from the Sm {A to the Sm {C phase, are reported. In a thin layer of material in the bookshelf" geometry, i.e., the sm ectic layers viewed edge-on, thin parallel stripes are observed running perpendicular to the sm ectic layers. These stripes are possibly consistent with the long thin hexagonal cells that we propose here.

A cknow ledgm ents

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